

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	IS&R	L1	5679	(257/84,91,94,99,103,432,620).C CLS.	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:06
2	BRS	L10	58	9 and superluminescent near3 "light emitting diode"	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:13
3	BRS	L11	2	4 and ("gain region" "absorber region" "absorbing region")	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:14
4	BRS	L12	2	11 and (facet facets)	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:14
5	BRS	L13	0	12 and (facet facets) near3 (disk "disk shaped")	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:14
6	BRS	L3	766	1 and (waveguide "light guide")	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:13
7	BRS	L4	3	3 and superluminescent near3 "light emitting diode"	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:13
8	BRS	L5	3	4 and (gain absorber absorbing) near5 region	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:13
9	BRS	L6	2	5 and (facet facets)	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:14
10	BRS	L7	0	6 and (facet facets) near3 (disk "disk shaped")	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:14
11	BRS	L8	150612	("light emitting device" "light emitting diode")	US-PGPUB; USPAT; JPO; DERWENT	2006/06/13 10:13
12	BRS	L9	9463	L8 and (waveguide "light guide")	US-PGPUB; USPAT; EPO; DERWENT	2006/06/13 10:13